

# **IRG7CH35UEF**

## **IRG7CH35UEF Information**

Heisener.com	Part Number Manufacturer Category Description Package	IRG7CH35UEF Infineon Technologies Discrete Semiconductor Products Transistors - IGBTs - Single IGBT 1200V ULTRA FAST DIE Die For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## **IRG7CH35UEF** Specifications

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Manufacturer Part Number	IRG7CH35UEF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	Die
Series	-
IGBT Type	-
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	-
Current - Collector Pulsed (Icm)	-
Vce(on) (Max) @ Vge, Ic	1.6V @ 15V, 5A
Power - Max	-
Switching Energy	-
Input Type	Standard
Gate Charge	85nC
Td (on/off) @ 25°C	30ns/160ns
Test Condition	600V, 20A, 10 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-40°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die
	Report errors?

### **IRG7CH35UEF Guarantees**



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

### **IRG7CH35UEF** Payment Methods



## **IRG7CH35UEF** Shipping Methods



If you have any question about IRG7CH35UEF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com